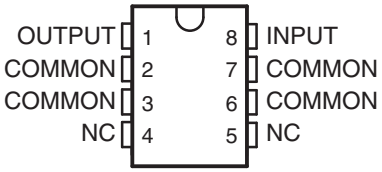
LOW-DROPOUT VOLTAGE REGULATORS

FEATURES

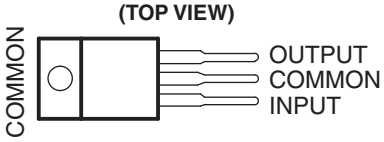
- Very Low Dropout Voltage, Less Than 0.6 V at 150 mA
- Very Low Quiescent Current
- TTL- and CMOS-Compatible Enable on TL751L Series
- 60-V Load-Dump Protection
- Reverse Transient Protection Down to –50 V
- Internal Thermal-Overload Protection
- Overvoltage Protection
- Internal Overcurrent-Limiting Circuitry
- Less Than 500-µA Disable (TL751L Series)

TL750L . . . D PACKAGE
(TOP VIEW)

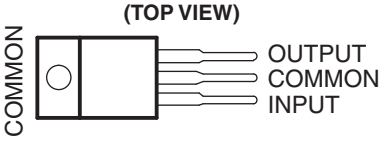


NC – No internal connection

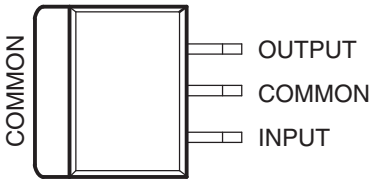
TL750L . . . KC PACKAGE
(TOP VIEW)



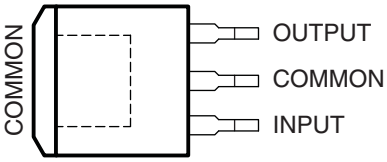
TL750L . . . KCS PACKAGE
(TOP VIEW)



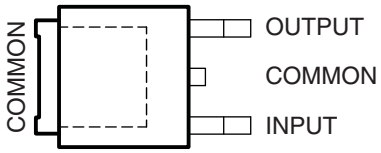
TL750L . . . KTE PACKAGE
(TOP VIEW)



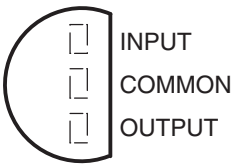
TL750L . . . KTT PACKAGE
(TOP VIEW)



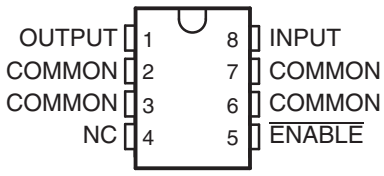
TL750L . . . KVU PACKAGE
(TOP VIEW)



TL750L . . . LP PACKAGE
(TO-92, TO-226AA)
(TOP VIEW)

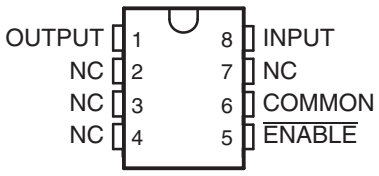


TL751L . . . D PACKAGE
(TOP VIEW)



NC – No internal connection

TL751L . . .P PACKAGE
(TOP VIEW)



NC – No internal connection

DESCRIPTION/ORDERING INFORMATION

The TL750L and TL751L series of fixed-output voltage regulators offer 5-V, 8-V, 10-V, and 12-V options. The TL751L series also has an enable (ENABLE) input. When ENABLE is high, the regulator output is placed in the high-impedance state. This gives the designer complete control over power up, power down, or emergency shutdown.

The TL750L and TL751L series are low-dropout positive-voltage regulators specifically designed for battery-powered systems. These devices incorporate overvoltage and current-limiting protection circuitry, along with internal reverse-battery protection circuitry to protect the devices and the regulated system. The series is fully protected against 60-V load-dump and reverse-battery conditions. Extremely low quiescent current during full-load conditions makes these devices ideal for standby power systems.

ORDERING INFORMATION(1)

T_J	V_O TYP AT 25°C	PACKAGE (2)		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 125°C	5 V	PowerFLEX™ – KTE	Reel of 2000	TL750L05CKTER	TL750L05C
		SOIC – D	Tube of 75	TL750L05CD	50L05C
			Reel of 2500	TL750L05CDR	
			Tube of 75	TL751L05CD	51L05C
			Reel of 2500	TL751L05CDR	
		TO-226/TO-92 – LP	Bulk of 1000	TL750L05CLP	750L05C
			Reel of 2000	TL750L05CLPR	
		TO-220 – KC	Tube of 50	TL750L05CKC	TL750L05C
		TO-220 – KCS	Tube of 50	TL750L05CKCS	TL750L05C
		TO-252 – KVU	Reel of 2500	TL750L05CKVUR	750L05C
		TO-263 – KTT	Reel of 500	TL750L05CKTTR	750L05C
	8 V	SOIC – D	Tube of 75	TL750L08CD	50L08C
			Reel of 2500	TL750L08CDR	
		TO-226/TO-92 – LP	Bulk of 1000	TL750L08CLP	750L08C
	10 V	PDIP – P	Tube of 50	TL751L10CP	TL751L10C
		SOIC – D	Tube of 75	TL750L10CD	50L10C
			Reel of 2500	TL750L10CDR	
			Tube of 75	TL751L10CD	51L10C
			Reel of 2500	TL751L10CDR	
		TO-226/TO-92 – LP	Bulk of 1000	TL750L10CLP	750L10C
			Reel of 2000	TL750L10CLPR	
	12 V	SOIC – D	Tube of 75	TL750L12CD	50L12C
			Reel of 2500	TL750L12CDR	
			Tube of 75	TL751L12CD	51L12C
			Reel of 2500	TL751L12CDR	
		TO-226/TO-92 – LP	Bulk of 1000	TL750L12CLP	750L12C

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

DEVICE COMPONENT COUNT	
Transistors	20
JFETs	2
Diodes	5
Resistors	16

Absolute Maximum Ratings(1)

over operating junction temperature range (unless otherwise noted)

			MIN	MAX	UNIT
	Continuous input voltage			26	V
	Transient input voltage(2)	T_A = 25°C		60	V
	Continuous reverse input voltage			–15	V
	Transient reverse input voltage	t ≤ 100 ms		–50	V
T_J	Operating virtual junction temperature			150	°C
	Lead temperature	1,6 mm (1/16 in) for 10 s		260	°C
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The transient input voltage rating applies to the waveform shown in Figure 1.

Package Thermal Data(1)

PACKAGE	BOARD	θ_{JC}	θ_{JA}
PDIP (P)	High K, JESD 51-7	57°C/W	85°C/W
PowerFLEX™ (KTE)	High K, JESD 51-5	3°C/W	23°C/W
SOIC (D)	High K, JESD 51-7	39°C/W	97°C/W
TO-226/TO-92 (LP)	High K, JESD 51-7	55°C/W	140°C/W
TO-220 (KC)	High K, JESD 51-5	3°C/W	19°C/W
TO-220 (KCS)	High K, JESD 51-5	3°C/W	19°C/W
TO-252 (KVU)	High K, JESD 51-5	–	30.3°C/W
TO-263 (KTT)	High K, JESD 51-5	18°C/W	25.3°C/W

(1) Maximum power dissipation is a function of $T_J(max)$, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) – T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

Recommended Operating Conditions

over recommended operating junction temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V_I	Input voltage		TL75xL05	6	26	V
			TL75xL08	9	26	
			TL75xL10	11	26	
			TL75xL12	13	26	
V_{IH}	High-level $\overline{\text{ENABLE}}$ input voltage		TL75xLxx	2	15	V
V_{IL} (1)	Low-level $\overline{\text{ENABLE}}$ input voltage	T_J = 25°C	TL75xLxx	–0.3	0.8	V
		T_J = 0°C to 125°C	TL75xLxx	–0.15	0.8	
I_O	Output current		TL75xLxx	0	150	mA
T_J	Operating virtual junction temperature		TL75xLxxC	0	125	°C

(1) The algebraic convention, in which the least positive (most negative) value is designated minimum, is used in this data sheet for $\overline{\text{ENABLE}}$ voltage levels and temperature only.

TL75xL05 Electrical Characteristics[1]

V_I = 14 V, I_O = 10 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TL750L05 TL751L05			UNIT
			MIN	TYP	MAX	
Output voltage	V_I = 6 V to 26 V, I_O = 0 to 150 mA	T_J = 25°C	4.8	5	5.2	V
		T_J = 0°C to 125°C	4.75		5.25	
Input regulation voltage	V_I = 9 V to 16 V			5	10	mV
	V_I = 6 V to 26 V			6	30	
Ripple rejection	V_I = 8 V to 18 V, f = 120 Hz		60	65		dB
Output regulation voltage	I_O = 5 mA to 150 mA			20	50	mV
Dropout voltage	I_O = 10 mA				0.2	V
	I_O = 150 mA				0.6	
Output noise voltage	f = 10 Hz to 100 kHz			500		µV
Quiescent current	I_O = 150 mA			10	12	mA
	V_I = 6 V to 26 V, I_O = 10 mA, T_J = 0°C to 125°C			1	2	
	$\overline{\text{ENABLE}}$ ≥ 2 V				0.5	

(1) Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-µF capacitor across the input and a 10-µF capacitor, with equivalent series resistance of less than 0.4 Ω, across the output.

TL75xL08 Electrical Characteristics[1]

V_I = 14 V, I_O = 10 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TL750L08 TL751L08			UNIT
			MIN	TYP	MAX	
Output voltage	V_I = 9 V to 26 V, I_O = 0 to 150 mA	T_J = 25°C	7.68	8	8.32	V
		T_J = 0°C to 125°C	7.6		8.4	
Input regulation voltage	V_I = 10 V to 17 V			10	20	mV
	V_I = 9 V to 26 V			25	50	
Ripple rejection	V_I = 11 V to 21 V, f = 120 Hz		60	65		dB
Output regulation voltage	I_O = 5 mA to 150 mA			40	80	mV
Dropout voltage	I_O = 10 mA				0.2	V
	I_O = 150 mA				0.6	
Output noise voltage	f = 10 Hz to 100 kHz			500		µV
Quiescent current	I_O = 150 mA			10	12	mA
	V_I = 9 V to 26 V, I_O = 10 mA, T_J = 0°C to 125°C			1	2	
	$\overline{\text{ENABLE}}$ ≥ 2 V				0.5	

(1) Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-µF capacitor across the input and a 10-µF capacitor, with equivalent series resistance of less than 0.4 Ω, across the output.

TL75xL10 Electrical Characteristics[1]

V_I = 14 V, I_O = 10 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TL750L10 TL751L10			UNIT
			MIN	TYP	MAX	
Output voltage	V_I = 11 V to 26 V, I_O = 0 to 150 mA	T_J = 25°C	9.6	10	10.4	V
		T_J = 0°C to 125°C	9.5		10.5	
Input regulation voltage	V_I = 12 V to 19 V			10	25	mV
	V_I = 11 V to 26 V			30	60	
Ripple rejection	V_I = 12 V to 22 V, f = 120 Hz		60	65		dB
Output regulation voltage	I_O = 5 mA to 150 mA			50	100	mV
Dropout voltage	I_O = 10 mA				0.2	V
	I_O = 150 mA				0.6	
Output noise voltage	f = 10 Hz to 100 kHz			700		μV
Quiescent current	I_O = 150 mA			10	12	mA
	V_I = 11 V to 26 V, I_O = 10 mA, T_J = 0°C to 125°C			1	2	
	$\overline{\text{ENABLE}}$ ≥ 2 V				0.5	

(1) Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF capacitor, with equivalent series resistance of less than 0.4 Ω, across the output.

TL75xL12 Electrical Characteristics[1]

V_I = 14 V, I_O = 10 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TL750L12 TL751L12			UNIT
			MIN	TYP	MAX	
Output voltage	V_I = 13 V to 26 V, I_O = 0 to 150 mA	T_J = 25°C	11.52	12	12.48	V
		T_J = 0°C to 125°C	11.4		12.6	
Input regulation voltage	V_I = 14 V to 19 V			15	30	mV
	V_I = 13 V to 26 V			20	40	
Ripple rejection	V_I = 13 V to 23 V, f = 120 Hz		50	55		dB
Output regulation voltage	I_O = 5 mA to 150 mA			50	120	mV
Dropout voltage	I_O = 10 mA				0.2	V
	I_O = 150 mA				0.6	
Output noise voltage	f = 10 Hz to 100 kHz			700		μV
Quiescent current	I_O = 150 mA			10	12	mA
	V_I = 13 V to 26 V, I_O = 10 mA, T_J = 0°C to 125°C			1	2	
	$\overline{\text{ENABLE}}$ ≥ 2 V				0.5	

(1) Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF capacitor, with equivalent series resistance of less than 0.4 Ω, across the output.

PARAMETER MEASUREMENT INFORMATION

The TL750L, TL751L series are low-dropout regulators. This means that capacitance loading is important to the performance of the regulator because it is a vital part of the control loop. The capacitor value and its equivalent series resistance (ESR) both affect the control loop and must be defined for the load range and temperature range. Figure 1 shows the recommended range of ESR for a given load with a 10-μF capacitor on the output.

TYPICAL CHARACTERISTICS

TL750L05
EQUIVALENT SERIES RESISTANCE
vs
LOAD CURRENT

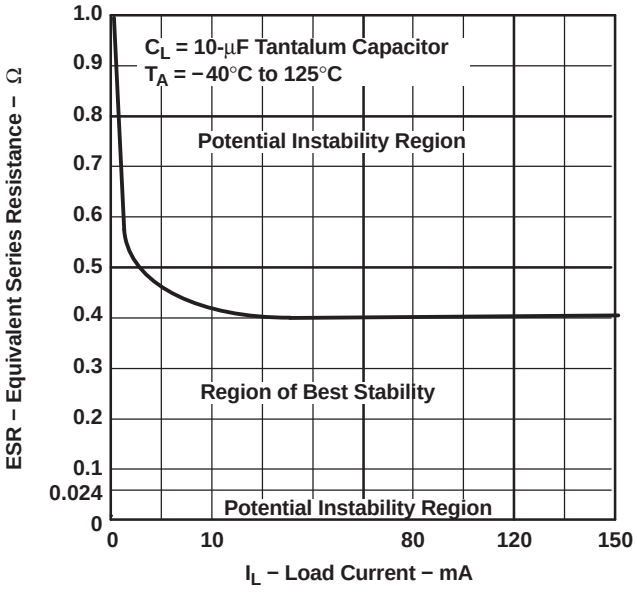


Figure 1.

TRANSIENT INPUT VOLTAGE
vs
TIME

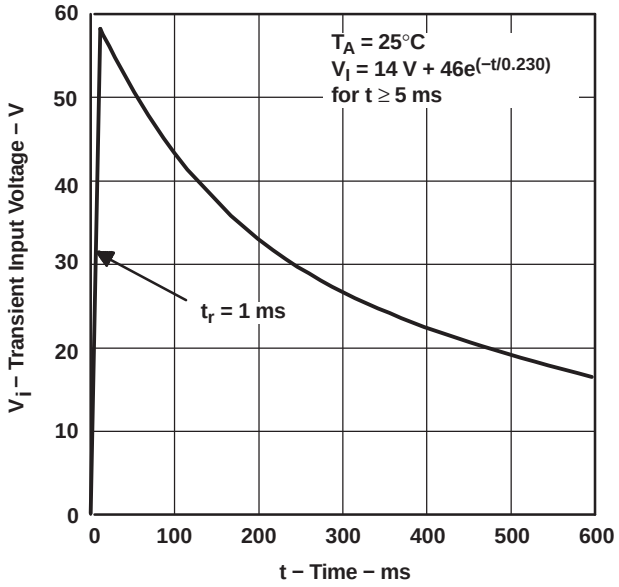


Figure 2.

TL750L05
INPUT CURRENT
vs
INPUT VOLTAGE

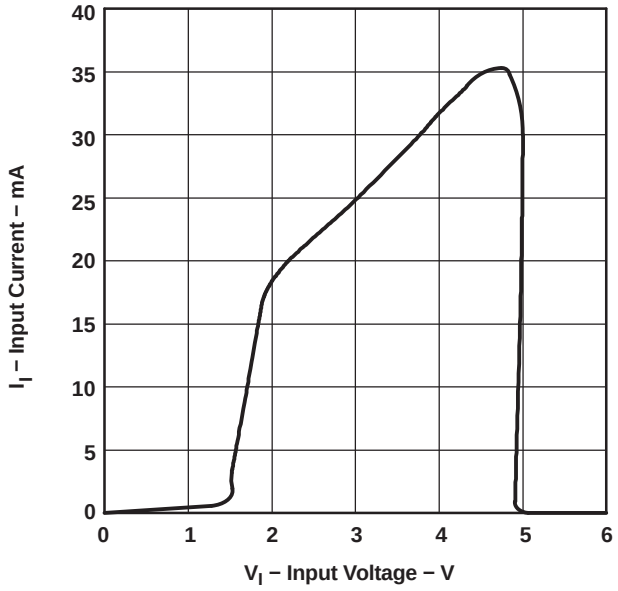


Figure 3.

TL750L12
INPUT CURRENT
vs
INPUT VOLTAGE

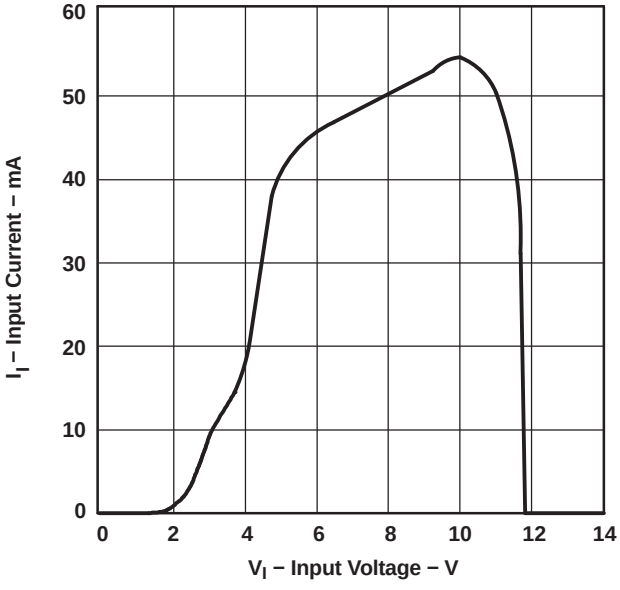


Figure 4.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TL750L05CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	50L05C	Samples
TL750L05CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	50L05C	Samples
TL750L05CKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	TL750L05C	Samples
TL750L05CKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	TL750L05C	Samples
TL750L05CKTTR	ACTIVE	DDPAK/ TO-263	KTT	3	500	Green (RoHS & no Sb/Br)	CU SN	Level-3-245C-168 HR	0 to 125	TL750L05C	Samples
TL750L05CKTTRG3	ACTIVE	DDPAK/ TO-263	KTT	3	500	Green (RoHS & no Sb/Br)	CU SN	Level-3-245C-168 HR	0 to 125	TL750L05C	Samples
TL750L05CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	750L05C	Samples
TL750L05CLP	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	750L05C	Samples
TL750L05CLPE3	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	750L05C	Samples
TL750L05CLPR	ACTIVE	TO-92	LP	3	2000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	750L05C	Samples
TL750L05CLPRE3	ACTIVE	TO-92	LP	3	2000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	750L05C	Samples
TL750L08CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 125	50L08C	Samples
TL750L08CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 125	50L08C	Samples
TL750L08CLP	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	750L08C	Samples
TL750L08CLPE3	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	750L08C	Samples
TL750L10CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	50L10C	Samples
TL750L10CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	50L10C	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TL750L10CLP	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	750L10C	Samples
TL750L10CLPR	ACTIVE	TO-92	LP	3	2000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	750L10C	Samples
TL750L12CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	50L12C	Samples
TL750L12CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	50L12C	Samples
TL750L12CLP	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	750L12C	Samples
TL751L05CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	51L05C	Samples
TL751L05CDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	51L05C	Samples
TL751L05CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	51L05C	Samples
TL751L05CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	51L05C	Samples
TL751L10CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	51L10C	Samples
TL751L10CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	51L10C	Samples
TL751L10CP	ACTIVE	PDIP	P	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	0 to 125	TL751L10C	Samples
TL751L12CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	51L12C	Samples
TL751L12CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	51L12C	Samples
TL751L12CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 125	51L12C	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

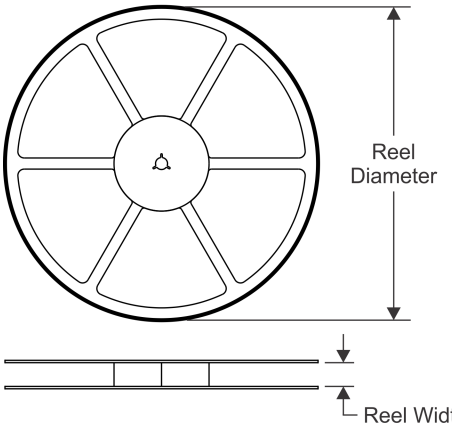
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

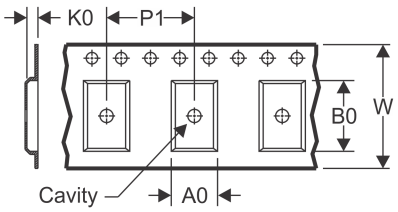
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

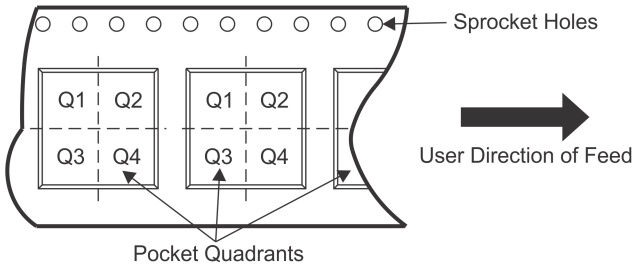


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

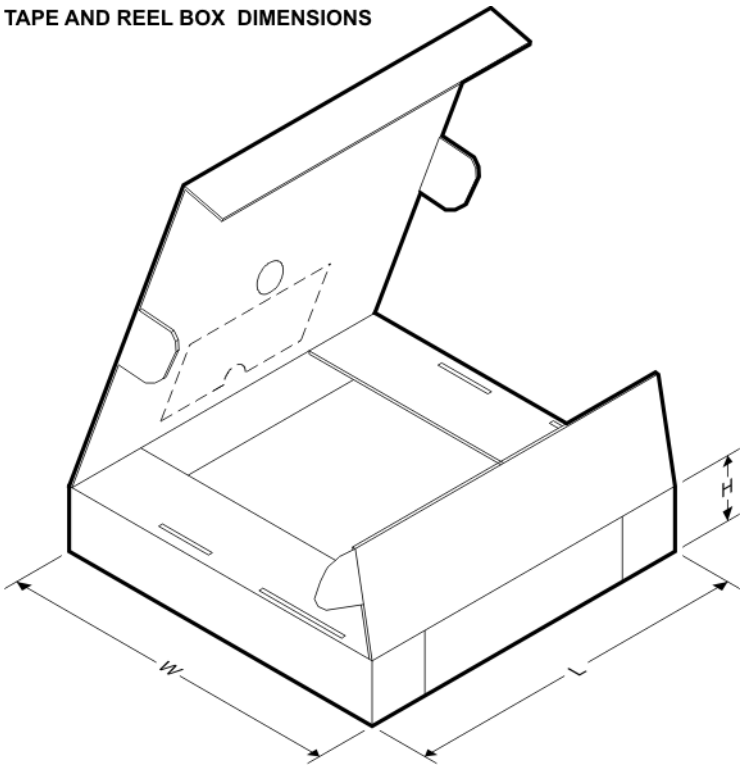
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL750L05CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL750L05CKTTR	DDPAK/ TO-263	KTT	3	500	330.0	24.4	10.8	16.1	4.9	16.0	24.0	Q2
TL750L05CKTTR	DDPAK/ TO-263	KTT	3	500	330.0	24.4	10.8	16.3	5.11	16.0	24.0	Q2
TL750L05CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
TL750L08CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL750L10CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL750L12CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL751L05CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL751L10CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL751L12CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

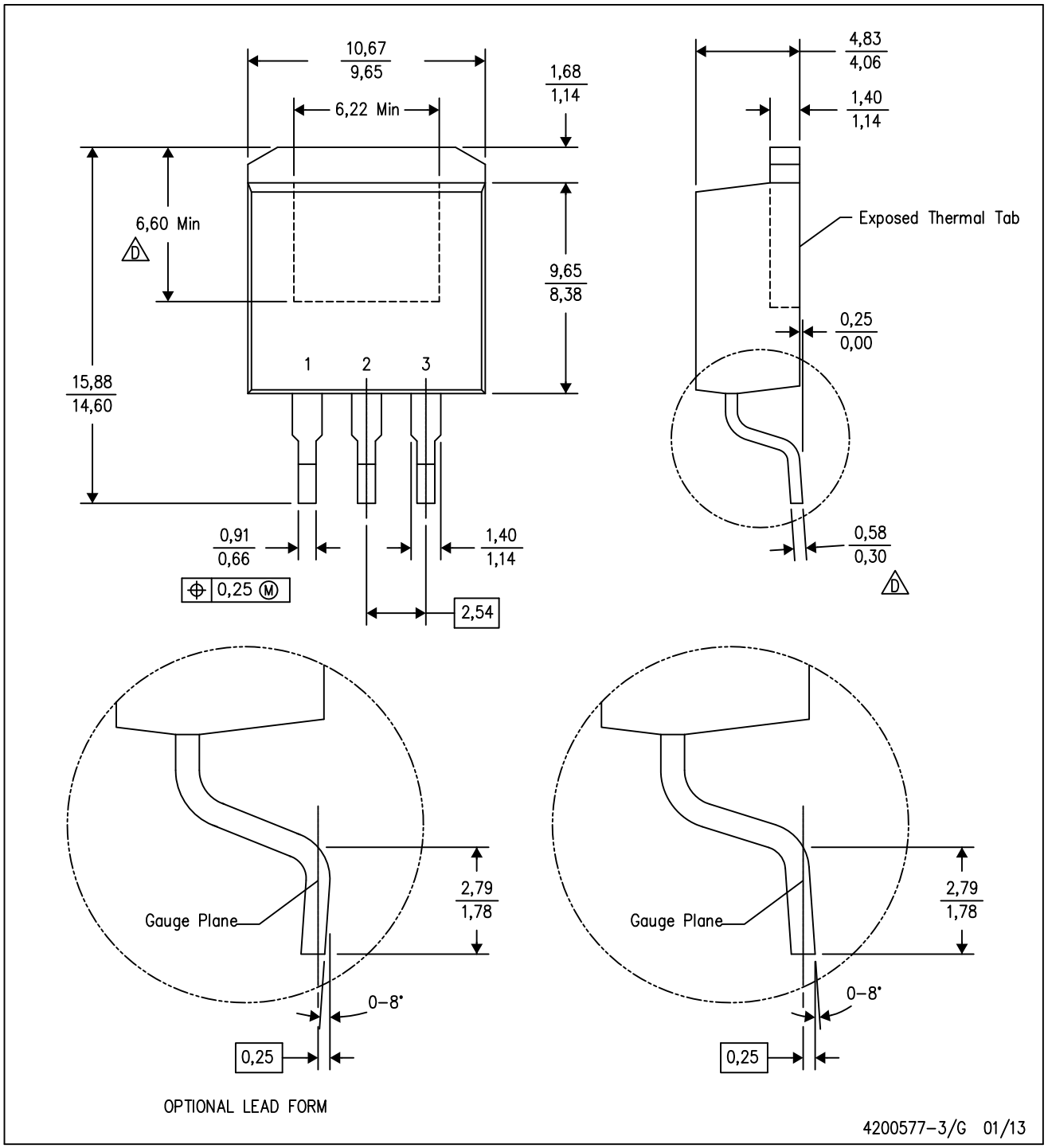
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

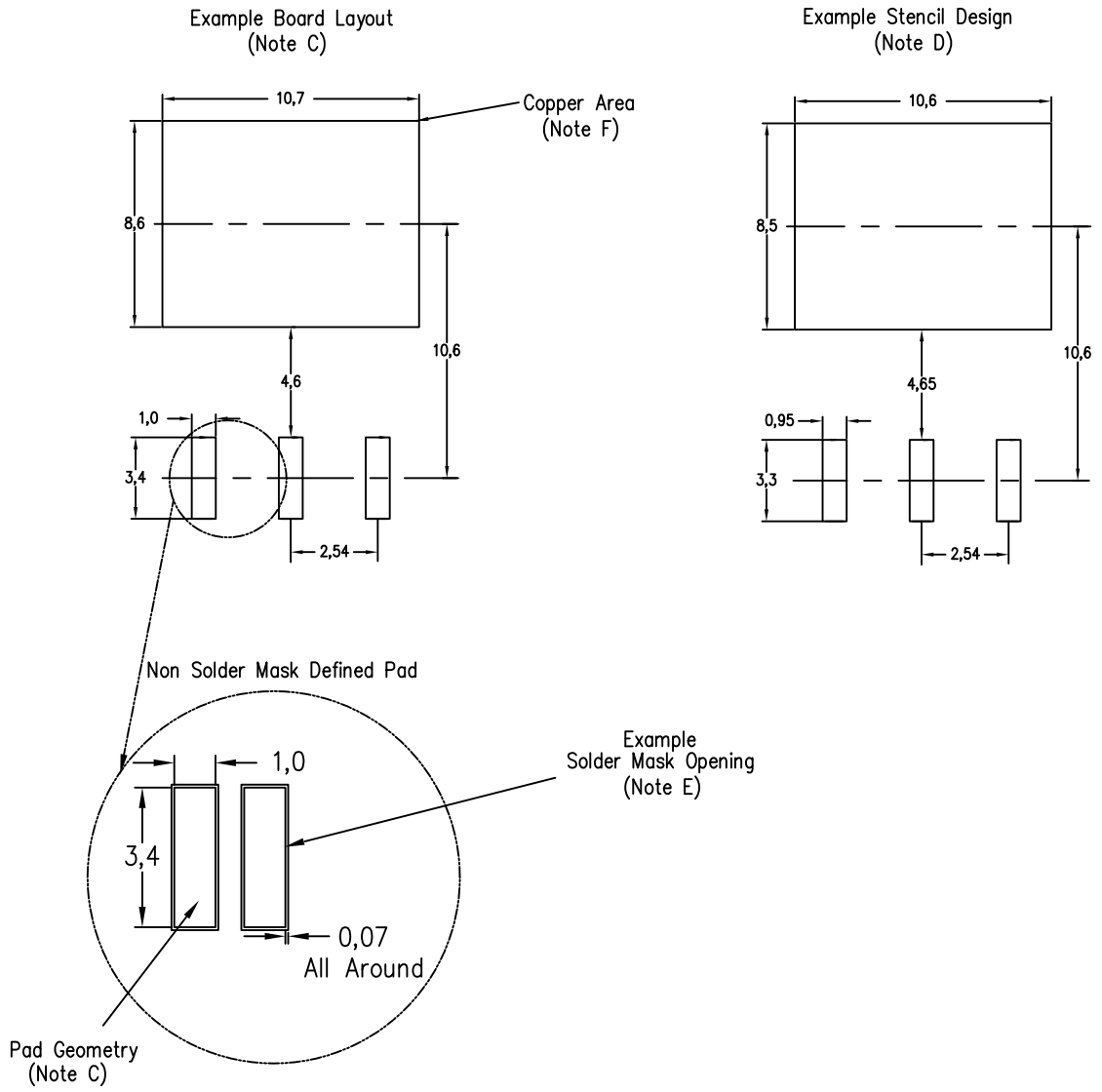
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL750L05CDR	SOIC	D	8	2500	340.5	338.1	20.6
TL750L05CKTTR	DDPAK/TO-263	KTT	3	500	350.0	334.0	47.0
TL750L05CKTTR	DDPAK/TO-263	KTT	3	500	340.0	340.0	38.0
TL750L05CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
TL750L08CDR	SOIC	D	8	2500	340.5	338.1	20.6
TL750L10CDR	SOIC	D	8	2500	340.5	338.1	20.6
TL750L12CDR	SOIC	D	8	2500	340.5	338.1	20.6
TL751L05CDR	SOIC	D	8	2500	340.5	338.1	20.6
TL751L10CDR	SOIC	D	8	2500	340.5	338.1	20.6
TL751L12CDR	SOIC	D	8	2500	340.5	338.1	20.6

KTT (R–PSFM–G3) PLASTIC FLANGE–MOUNT PACKAGE

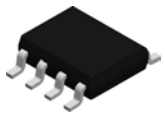


NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0.005 (0,13) per side.
D. Falls within JEDEC TO–263 variation AA, except minimum lead thickness and minimum exposed pad length.

KTT (R–PSFM–G3) PLASTIC FLANGE–MOUNT PACKAGE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–SM–782 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
F. This package is designed to be soldered to a thermal pad on the board. Refer to the Product Datasheet for specific thermal information, via requirements, and recommended thermal pad size. For thermal pad sizes larger than shown a solder mask defined pad is recommended in order to maintain the solderable pad geometry while increasing copper area.

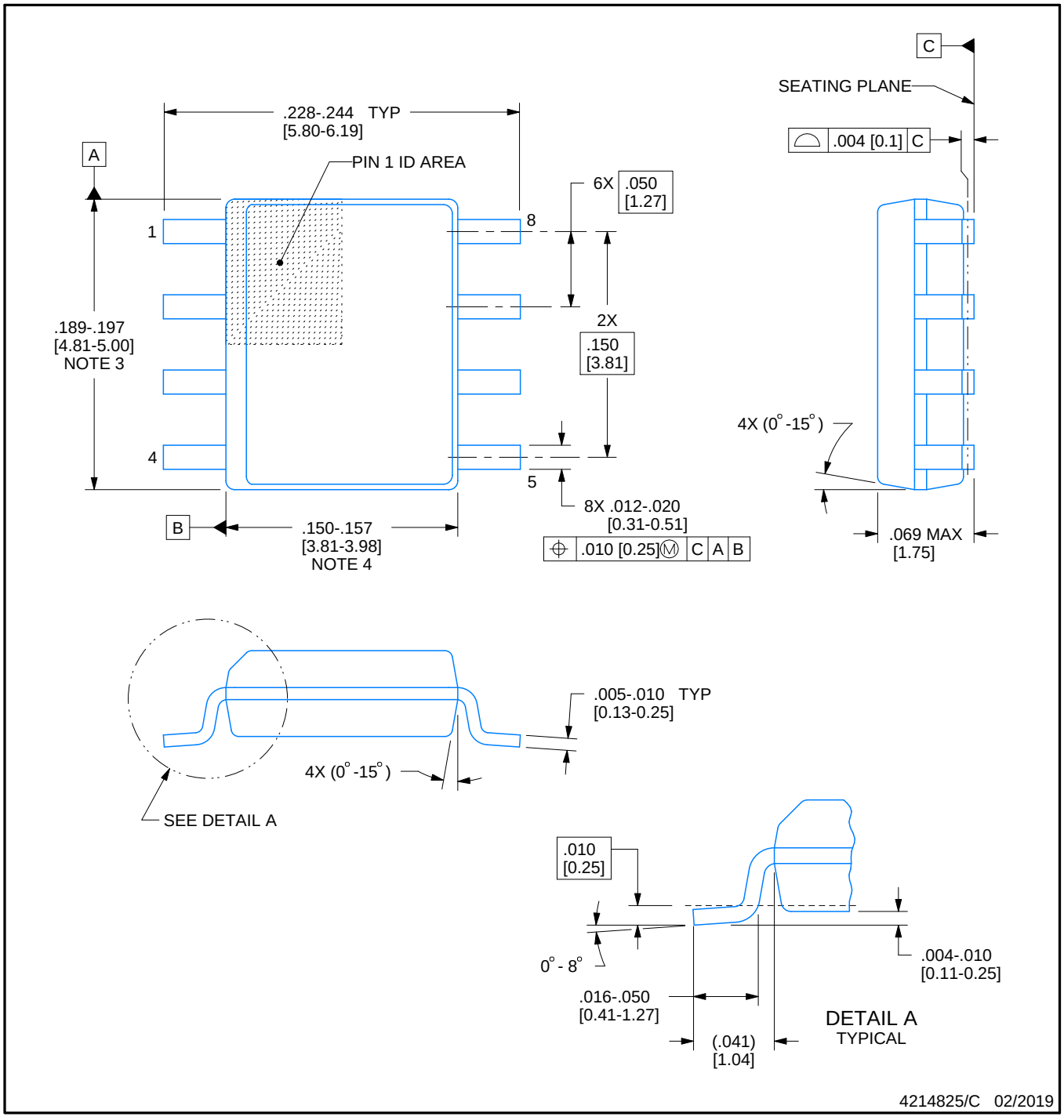


PACKAGE OUTLINE

D0008A

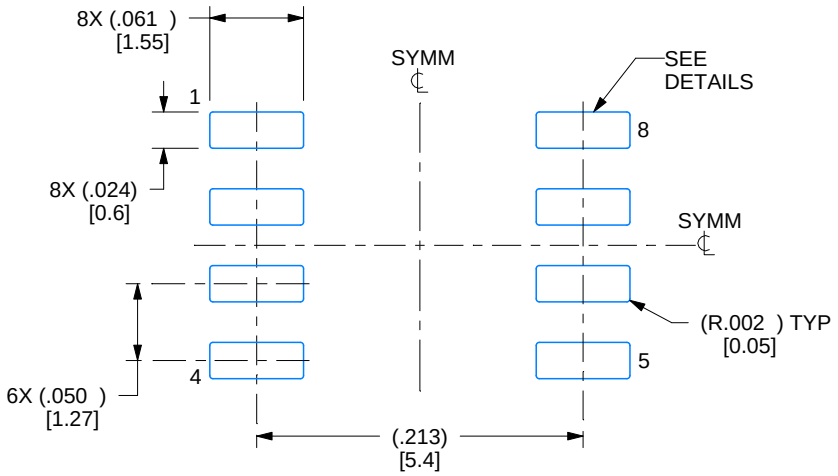
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

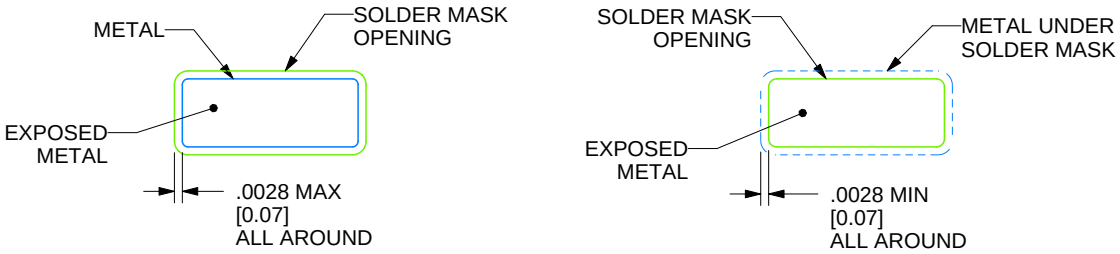


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

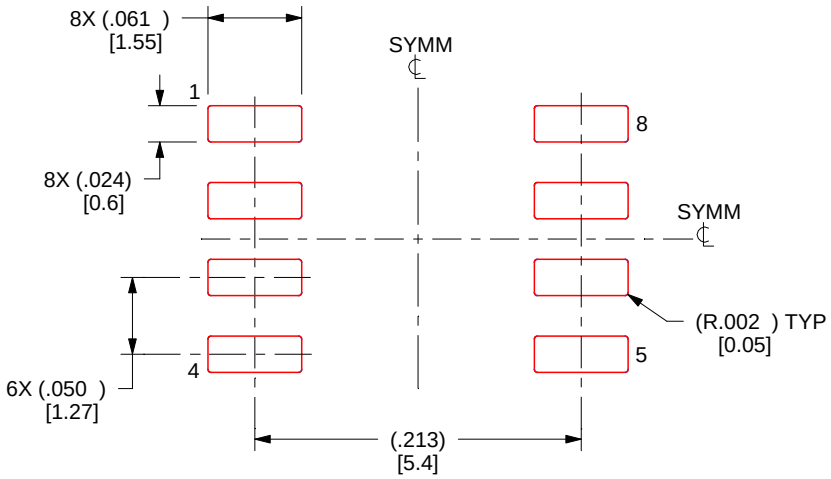
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



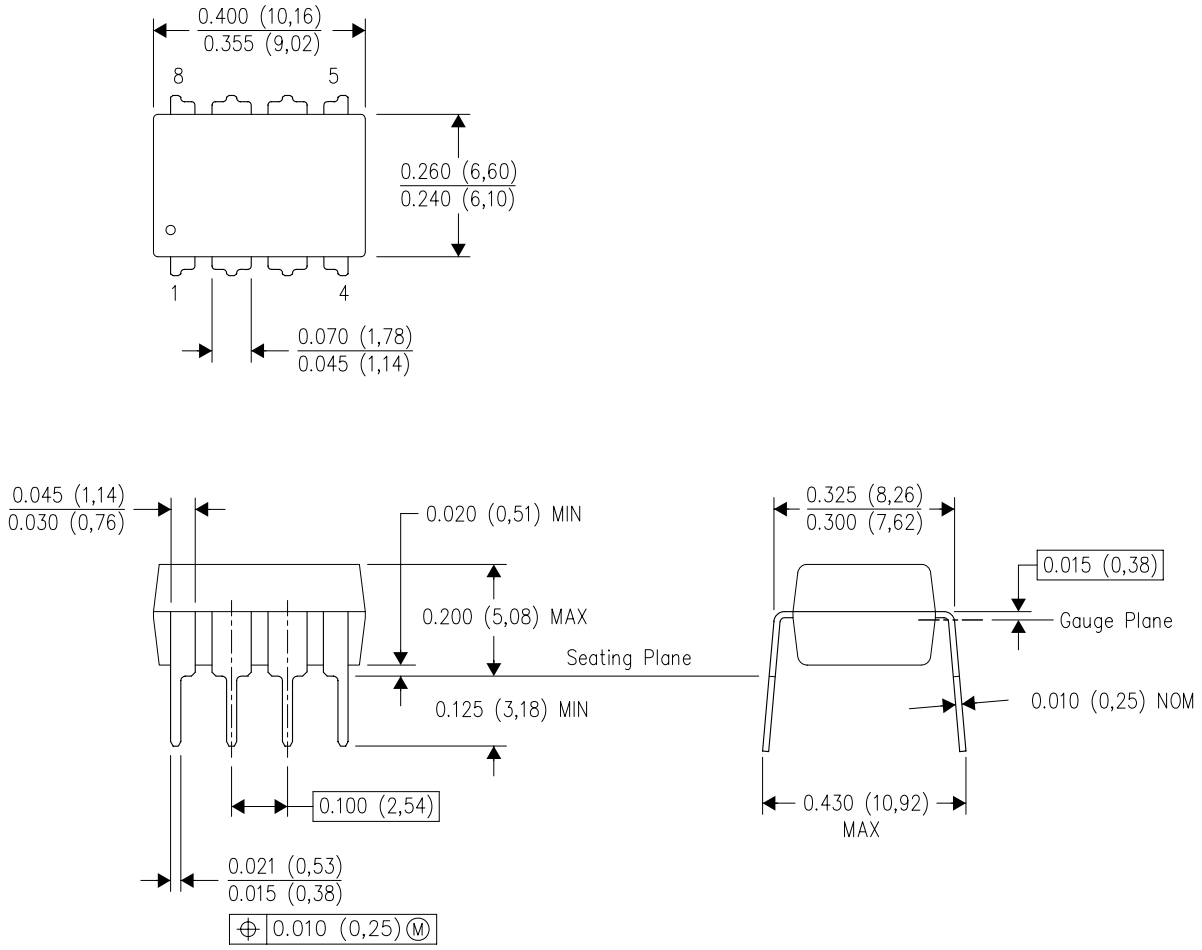
SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

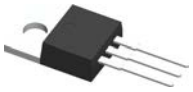
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R–PDIP–T8) PLASTIC DUAL–IN–LINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001 variation BA.

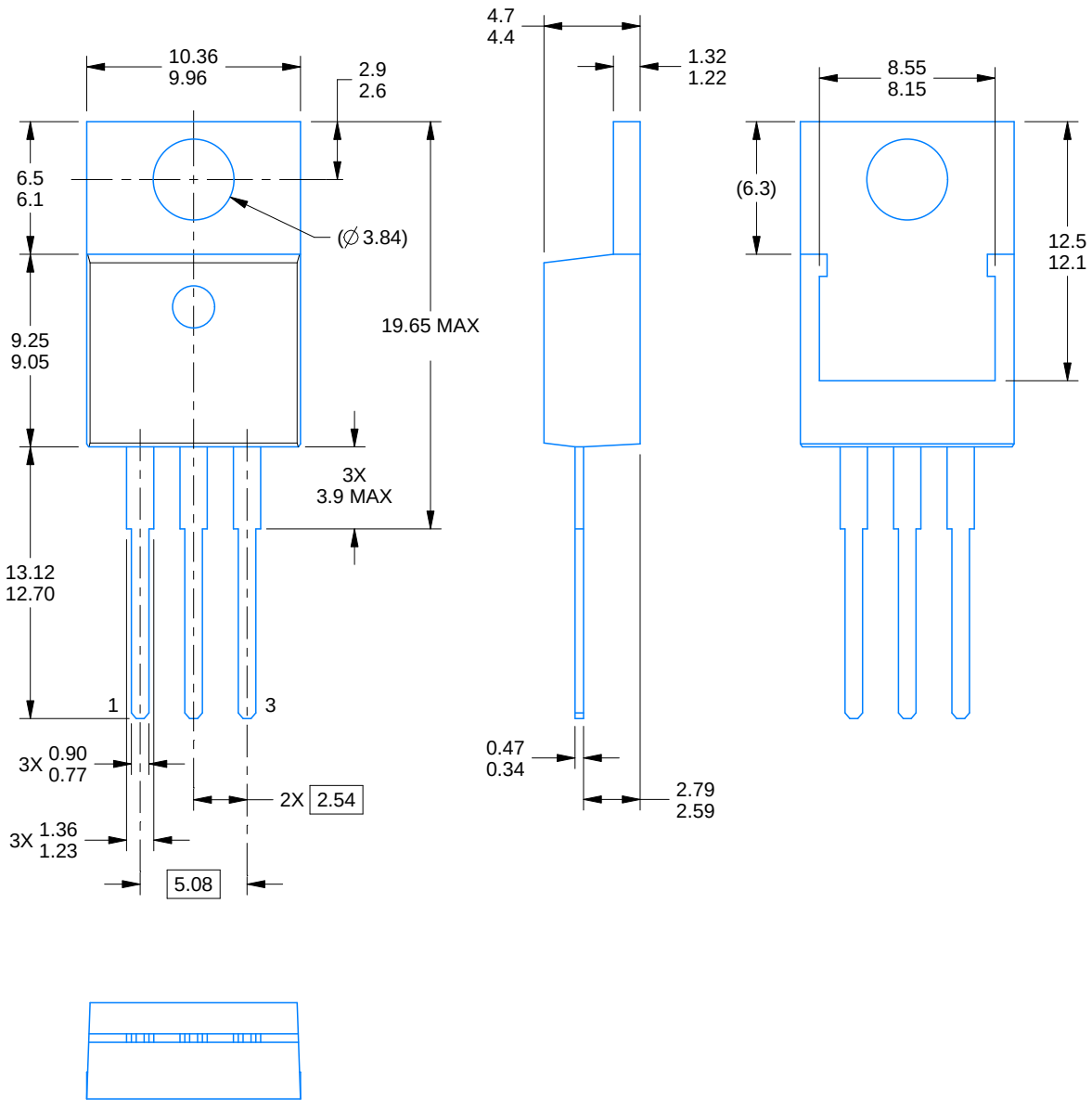
KCS0003B



PACKAGE OUTLINE

TO-220 - 19.65 mm max height

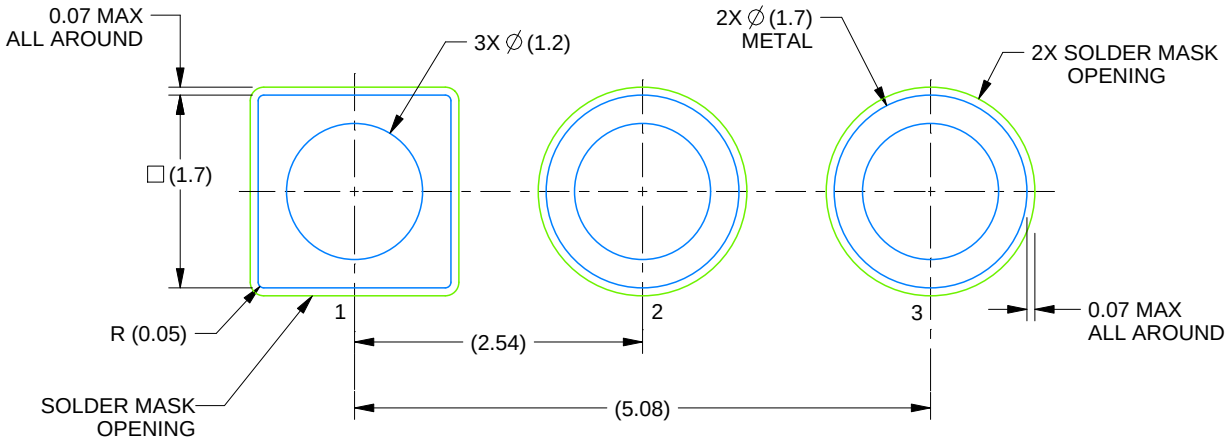
TO-220



4222214/B 08/2018

NOTES:

1. Dimensions are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-220.



LAND PATTERN EXAMPLE
NON-SOLDER MASK DEFINED
SCALE:15X

4222214/B 08/2018

GENERIC PACKAGE VIEW

LP 3 TO-92 - 5.34 mm max height

TRANSISTOR OUTLINE

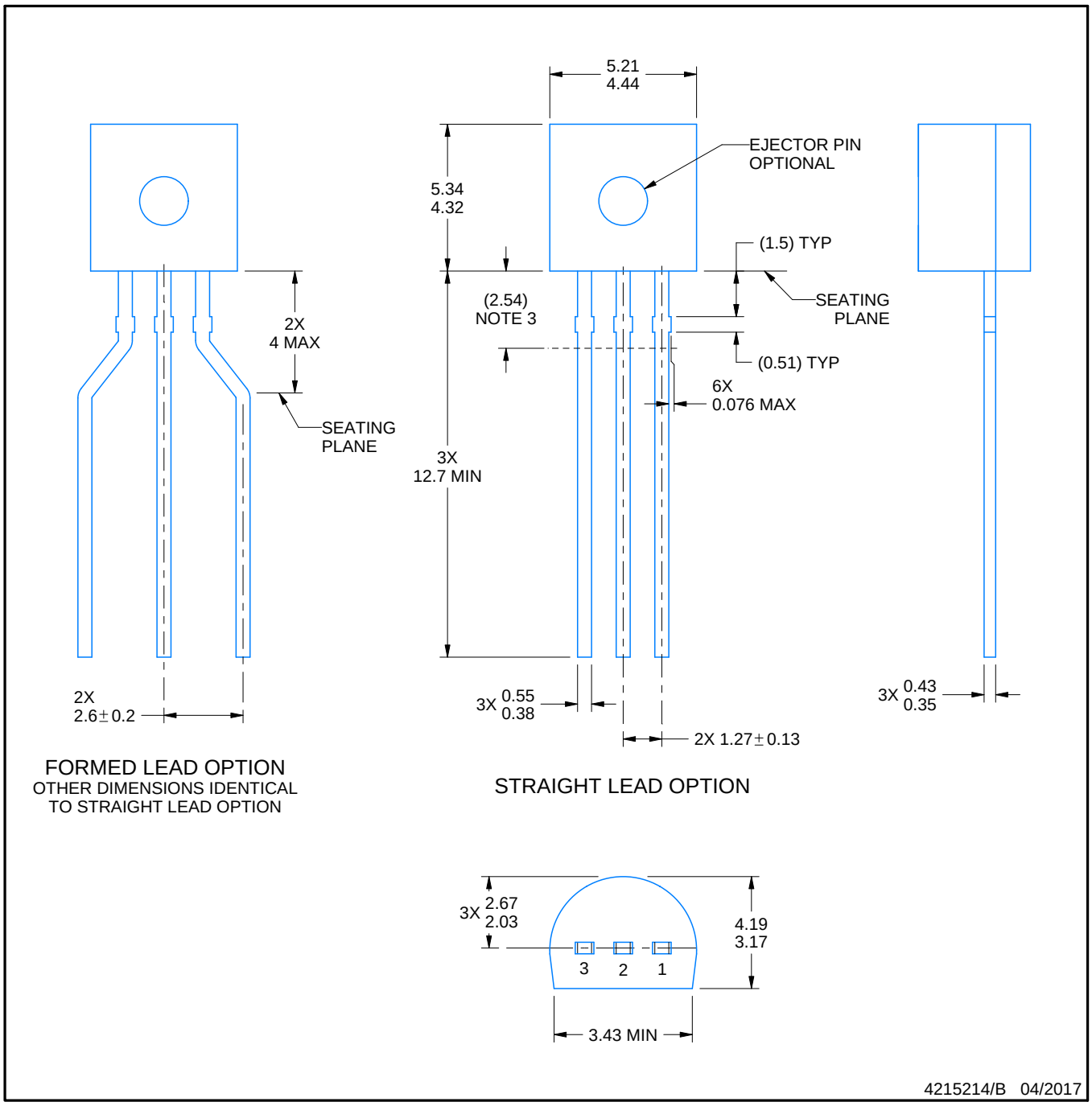
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

LP0003A

PACKAGE OUTLINE

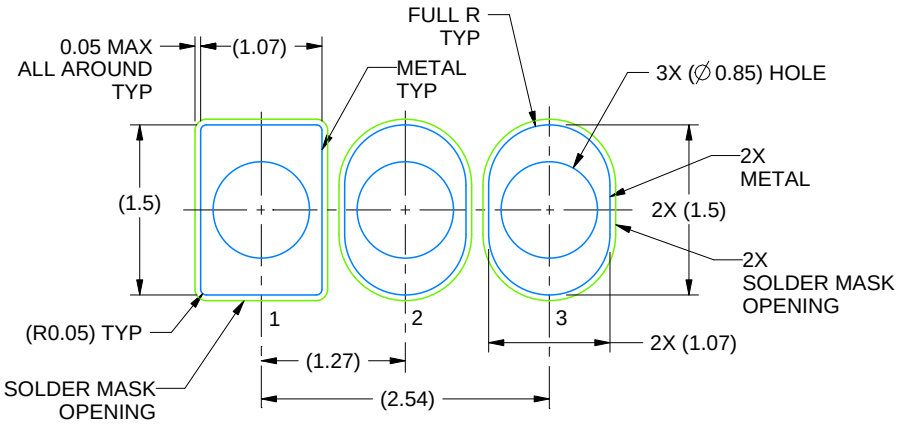
TO-92 - 5.34 mm max height

TO-92

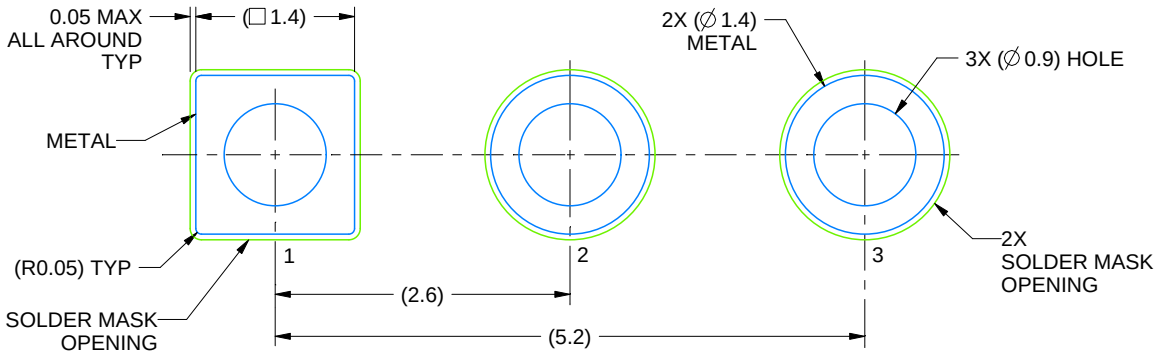


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Lead dimensions are not controlled within this area.
4. Reference JEDEC TO-226, variation AA.
5. Shipping method:
   a. Straight lead option available in bulk pack only.
   b. Formed lead option available in tape and reel or ammo pack.
   c. Specific products can be offered in limited combinations of shipping medium and lead options.
   d. Consult product folder for more information on available options.



LAND PATTERN EXAMPLE
STRAIGHT LEAD OPTION
NON-SOLDER MASK DEFINED
SCALE:15X



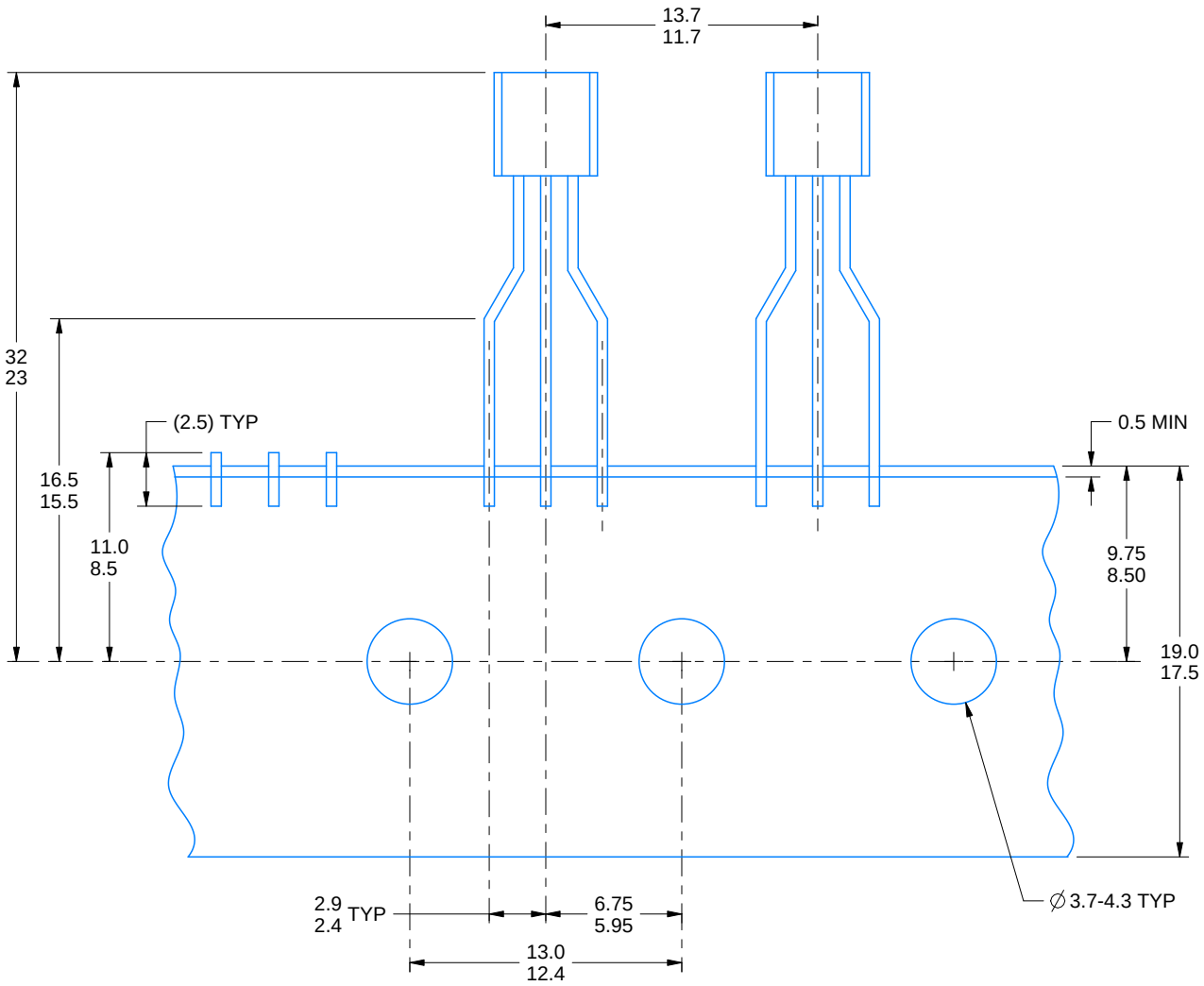
LAND PATTERN EXAMPLE
FORMED LEAD OPTION
NON-SOLDER MASK DEFINED
SCALE:15X

4215214/B 04/2017

LP0003A

TO-92 - 5.34 mm max height

TO-92



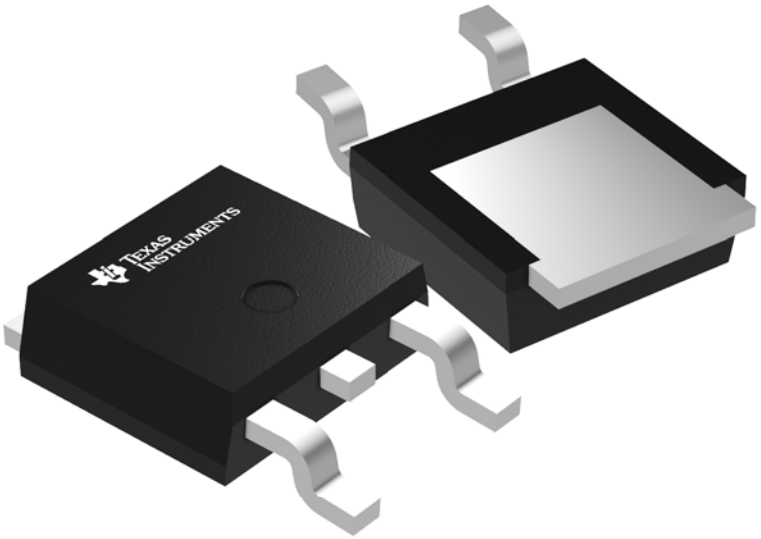
FOR FORMED LEAD OPTION PACKAGE

4215214/B 04/2017

KVU 3

TO-252 - 2.52 mm max height

TRANSISTOR OUTLINE



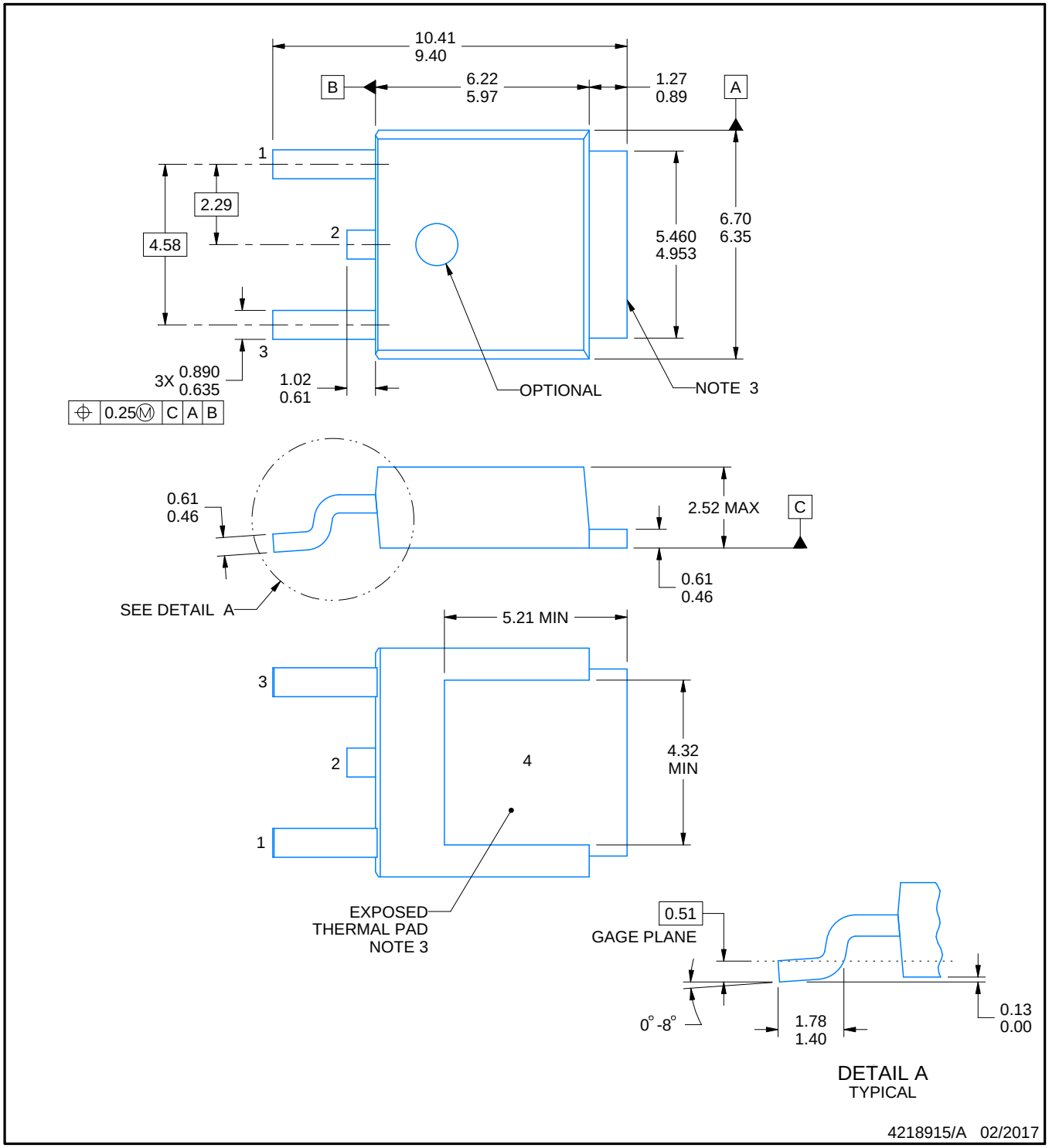
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

PACKAGE OUTLINE

KVU0003A

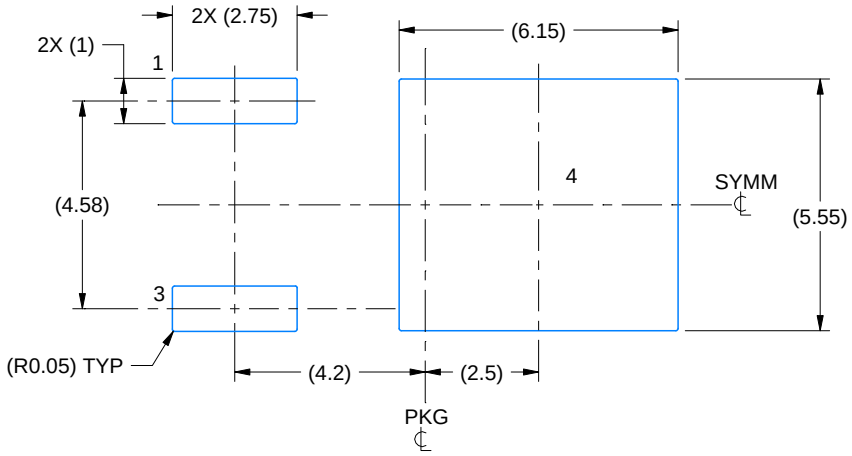
TO-252 - 2.52 mm max height

TO-252

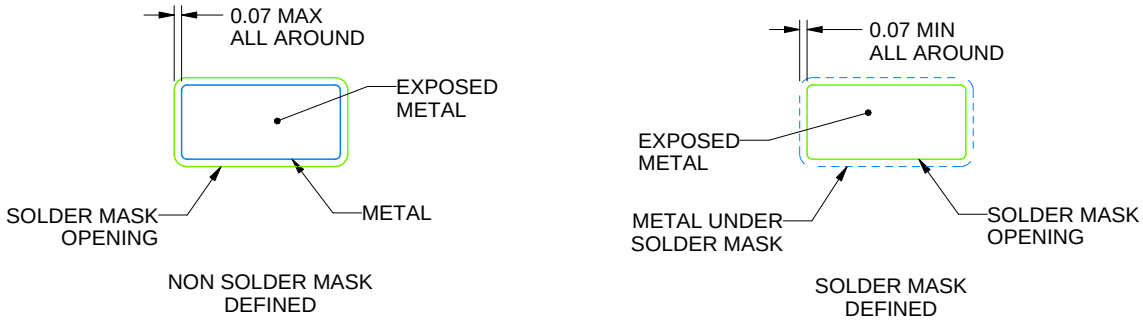


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Shape may vary per different assembly sites.
4. Reference JEDEC registration TO-252.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:6X



SOLDER MASK DETAILS
NOT TO SCALE

4218915/A 02/2017

NOTES: (continued)

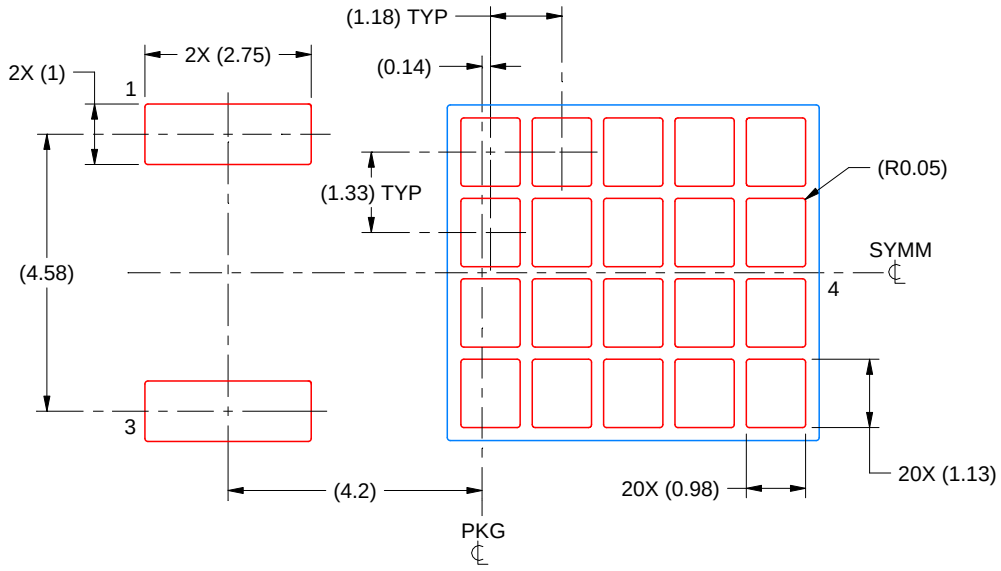
5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).
6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

KVU0003A

TO-252 - 2.52 mm max height

TO-252



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
65% PRINTED SOLDER COVERAGE BY AREA
SCALE:8X

4218915/A 02/2017

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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